

Perpendicular magnetic anisotropy in TmIG and GdIG thin films

C. Holzmann,¹ O. Ciubotariu,¹ and M. Albrecht¹

¹*Institute of Physics, University of Augsburg, 86159 Augsburg, Germany*

Yttrium iron garnet (YIG) has been well studied as its low Gilbert damping parameter promises use in spintronic devices and sensors. Recently, research turns towards the similar rare earth iron garnets with a more complex magnetic structure, such as the ferrimagnetic insulators thulium iron garnet (TmIG) and gadolinium iron garnet (GdIG). In thin film form, magnetic shape anisotropy favors an in-plane magnetic easy axis. However, thin films grown on lattice-mismatched sGGG or GSGG substrates exhibit a magnetoelastic anisotropy favoring an out-of-plane easy axis [1,2]. Therefore, tuning of the magnetic easy axis and ultimately perpendicular magnetic anisotropy (PMA) was achieved, enabling further research in the field of spintronics.

In our study, TmIG and GdIG thin films were grown epitaxially on sGGG and GSGG substrates by pulsed laser deposition (PLD). To ensure single crystalline growth of stoichiometric thin films and a smooth surface morphology the films are prepared at elevated temperatures of 600 – 620°C, with low deposition rates of 0.01 – 0.03 $\frac{\text{nm}}{\text{s}}$ and in an oxygen atmosphere of $p_{\text{O}_2} = 0.04$ mbar and 0.02 mbar for TmIG and GdIG, respectively.

The PLD grown TmIG/sGGG and GdIG/GSGG thin films show PMA around room temperature [1]. Furthermore, for TmIG a gradual strain relaxation with increasing film thickness and a subsequent loss of PMA for 200 nm thick films is observed [1]. The antiferromagnetically coupled Gd^{3+} and the net Fe^{3+} magnetic sublattices of GdIG possess different thermal characteristics, resulting in a magnetic compensation point. The GdIG thin films with thicknesses between 15 nm and 200 nm show a magnetic compensation temperature in the range between 200 K and 300 K, affected by the induced strain as well as the film stoichiometry. Additionally, a change from PMA to an in-plane easy axis below roughly 150 K due to the strongly increased magnetic shape anisotropy is observed for the 30 nm thick film. The smooth surface morphology with a root mean square roughness of 0.2 ± 0.1 nm is a key prerequisite for future research exploiting surface effects like the inverse spin Hall effect.

References:

- [1] Ciubotariu O., Semisalova A., Lenz K., Albrecht M. Strain-induced perpendicular magnetic anisotropy and Gilbert damping of $\text{Tm}_3\text{Fe}_5\text{O}_{12}$ thin films. *Scientific Reports* 9, 17474 (2019).
- [2] Kubota M., Tsukazaki A., Kagawa F. et al. Stress-induced perpendicular magnetization in epitaxial iron garnet thin films. *Applied Physics Express* 5, 103002 (2012).